TMAG5328 抵抗および電圧で調整可能、低消費電力、ホール・エフェクト・スイッチ

1 特長

- 電源電圧範囲:1.65V～5.5V
- 動作温度:-40℃～125℃
- B_{OP} を 2mT～15mT で調整可能
  - 2kΩ～15kΩ の抵抗を使用
  - または 160mV～1200mV の電圧源
- オムニポーラ のホール スイッチ
- プッシュプル出力
- 低消費電力
  - 20Hz のデューティ サイクル (A1D バージョン): 1.4μA
  - 連続時間 (A1Z バージョン):1.8mA
- 業界標準の SOT-23 パッケージとピン配置

2 アプリケーション

- バッテリ駆動時間が重要な位置センシング
- 電気メーターの改ざん検出
- 携帯電話、ラップトップ、またはタブレットのケース･センシング
- 電子ロック、煙感知器、家電機器
- 医療機器、IoT システム
- バルブまたはソレノイドの位置検出
- 非接触式の診断または起動

3 概要

TMAG5328 デバイスは、高精度、低消費電力、抵抗で調整可能、低電圧で動作するホール エフェクト スイッチ センサです。

外付け抵抗 により、デバイス動作の B_{OP} 値を設定します。簡単な式によって、設計に対する適切な B_{OP} 値を設定するために必要な抵抗値を容易に計算できます。ヒステリシスの値は固定であるため、B_{RP} の値は B_{OP}-ヒステリシスとして定義されます。

TMAG5328 は調整可能なスレッショルド機能を搭載しており、ユーザーはプロトタイプの設計を迅速に実施し、予期しない変更が発生した場合に直前で変更を加えることができるので、さまざまなプラットフォームでの再利用が可能です。

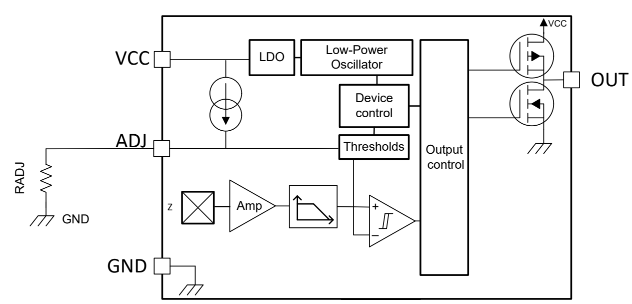
印加されている磁束密度が B_{OP} スレッショルドを超えると、デバイスは LOW 電圧を出力します。出力は、磁束密度が B_{RP} を下回るまで Low のまま維持され、その後、デバイスのオプションにより、出力が High 電圧を駆動します。このデバイスには発振器が内蔵されており、磁界をサンプリングして、消費電流を最小限に抑えるため出力を 20Hz (A1D バージョン) で更新するか、あるいは連続的 (A1Z バージョン) に更新します。TMAG5328 は、オムニポーラ磁気応答を採用しています。

このデバイスは、1.65V～5.5V の V_{CC} 範囲で動作し、標準の SOT-23-6 パッケージで供給されます。

パッケージ情報

部品番号	パッケージ(1)	パッケージ サイズ(2)
TMAG5328	DBV (SOT-23、6)	2.9mm × 2.8mm

(1) 供給されているすべてのパッケージについては、セクション 10 を参照してください。
(2) パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



代表的な回路図

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4 Pin Configuration and Functions

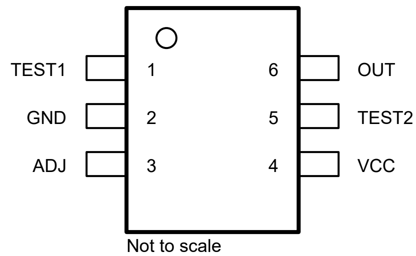


図 4-1. DBV Package 6-Pin SOT-23 Top View

表 4-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	SOT-23		
GND	2	—	Ground reference
OUT	6	O	Omnipolar output that responds to north and south magnetic poles
VCC	4	—	1.65V to 5.5V power supply. TI recommends connecting this pin to a ceramic capacitor to ground with a value of at least 0.1μF
ADJ	3	I	This pin is used to set the thresholds up. Can either be connected to a resistor or voltage source.
TEST1	1	—	TI recommends to leave this pin floating
TEST2	5	—	TI recommends connecting this pin to GND

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Power Supply Voltage	V_{CC}	–0.3	5.5	V
Pin Voltage	OUT, TEST1	–0.3	V_{CC} + 0.3	V
	TEST2	–0.3	0.3	
	ADJ	–0.3	5.5	
Pin current	OUT, TEST1	–5	5	mA
Magnetic Flux Density, BMAX		Unlimited		T
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	±2000	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002, all pins(2)	± 500	

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Power supply voltage	1.65	5.5	V
V_{IO}	Pin Voltage. OUT, TEST1	0	V_{CC}	V
	Pin Voltage. TEST2	0	0	
	Pin Voltage. ADJ	0	5	
Io	Pin current. OUT, TEST1	–5	5	mA
T_A	Ambient temperature	–40	125	°C

5.4 Thermal Information

THERMAL METRIC[(1)]		TMAG5328 SOT-23 (DBV) 6 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	167.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	84.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	52.2	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	32	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	51.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	–	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

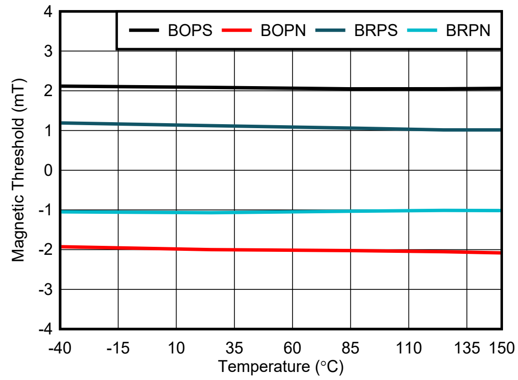
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ADJ pin						
ADJ_ICC	Current output source			80		µA
ADJ_C	Maximum external capacitance				50	pF
PUSH-PULL OUTPUT DRIVER						
V_{OH}	High-level output voltage	I_{OUT} = –0.5mA	Vcc – 0.35	Vcc – 0.1		V
V_{OL}	Low-level output voltage	I_{OUT} = 0.5mA		0.1	0.3	V
TMAG5328A1D						
fs	Frequency of magnetic sampling			20		Hz
ts	Period of magnetic sampling			50		ms
t_{ACTIVE}	Active time period			65		µs
$I_{CC(PK)}$	Peak current consumption			1.8	3	mA
$I_{CC(SLP)}$	Sleep current consumption			300	600	nA
$I_{CC(AVG)}$	Average current consumption	V_{CC} = 3.3V T_A = 25°C		1.4	1.6	µA
		V_{CC} = 1.65V to 5.5V			2.3	
TMAG5328A1Z						
f_{BW}	Signal bandwidth			20		kHz
$I_{CC(AVG)}$	Average current consumption	V_{CC} = 1.65V to 5.5V		1.8	2.1	mA
ALL VERSIONS						
P_{OS}	Power-on state without external magnetic field	$V_{CC} > V_{CCMIN}$		High		
t_{ON}	Power-on time			125		µs

5.6 Magnetic Characteristics

over operating free-air temperature range (unless otherwise noted)

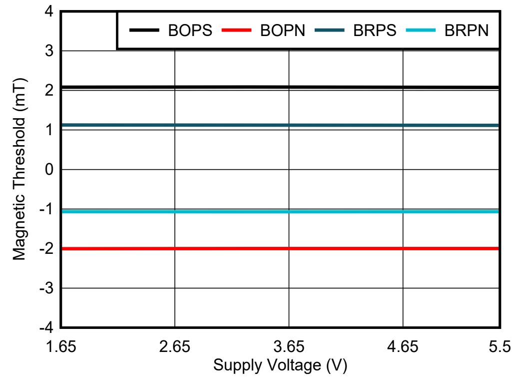
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
TMAG5328A1D						
$B_{OP(Range\ A)}$	Adjustable Operate Point		±2		±15	mT
$B_{RP(Range\ A)}$	Adjustable Release Point		±1		±14	mT
$V_{ADJ\ (Range\ A)}$	Voltage range		160		1200	mV
$R_{ADJ\ (Range\ A)}$	Resistor range		2		15	kOhm
$B_{OP}(R_{ADJ})$	B_{OP}/R			±1		mT/ kOhm
$B_{OP\_ACC}(R_{ADJ})$	B_{OP} Accuracy (B_{OPSET} ± $B_{OP(MAX/MIN)}$)/B_{OPSET}	2mT ≤ B_{OPSET} < 6mT	–0.85		0.85	mT
		6mT ≤ B_{OPSET} ≤ 15mT	–1.75		1.75	
$B_{RP\_ACC}(R_{ADJ})$	B_{RP} Accuracy (B_{RPSET} ± $B_{RP(MAX/MIN)}$)/B_{RPSET}	2mT ≤ B_{OPSET} < 6mT	–1		1	
		6mT ≤ B_{OPSET} ≤ 15mT	–2.1		2.1	
$B_{HYSA}(R_{ADJ})$	Magnetic hysteresis	$\|B_{OP} – B_{RP}\|$	0.25	1	1.6	
TMAG5328A1Z						
$B_{OP(Range\ A)}$	Adjustable Operate Point		±2		±15	mT
$B_{RP(Range\ A)}$	Adjustable Release Point		±1.5		±14.5	mT
$V_{ADJ\ (Range\ A)}$	Voltage range		160		1200	mV
$R_{ADJ\ (Range\ A)}$	Resistor range		2		15	kOhm
$B_{OP}(R_{ADJ})$	B_{OP}/R			±1		mT/ kOhm
$B_{OP\_ACC}(R_{ADJ})$	B_{OP} Accuracy (B_{OPSET} ± $B_{OP(MAX/MIN)}$)/B_{OPSET}	2mT ≤ B_{OPSET} < 6mT	–0.85		0.85	mT
		6mT ≤ B_{OPSET} ≤ 15mT	–1.75		1.75	mT
$B_{RP\_ACC}(R_{ADJ})$	B_{RP} Accuracy (B_{RPSET} ± $B_{RP(MAX/MIN)}$)/B_{RPSET}	2mT ≤ B_{OPSET} < 6mT	–1		1	mT
		6mT ≤ B_{OPSET} ≤ 15mT	–2.1		2.1	mT
$B_{HYSA}(R_{ADJ})$	Magnetic hysteresis	$\|B_{OP} – B_{RP}\|$	0.04	0.5	1.2	mT

5.7 Typical Characteristics



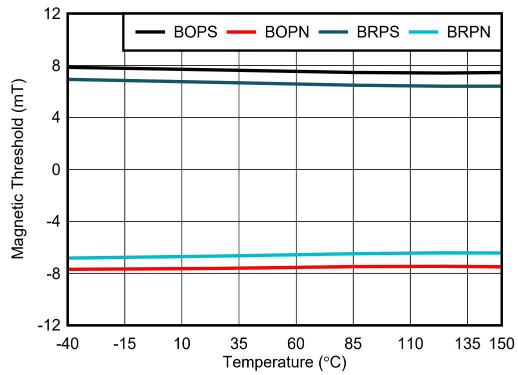
V_{CC} = 3.3V
Version: A1D

図 5-1. 2mT Magnetic Threshold vs Temperature



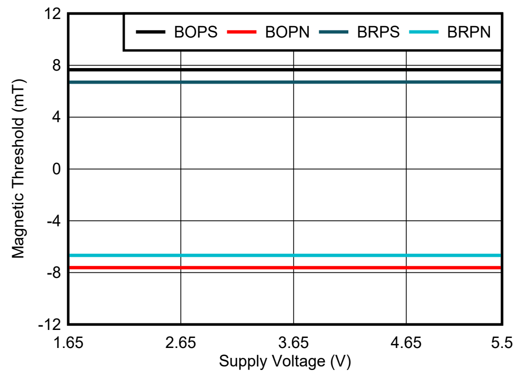
T_A = 25°C
Version: A1D

図 5-2. 2mT Magnetic Threshold vs Supply



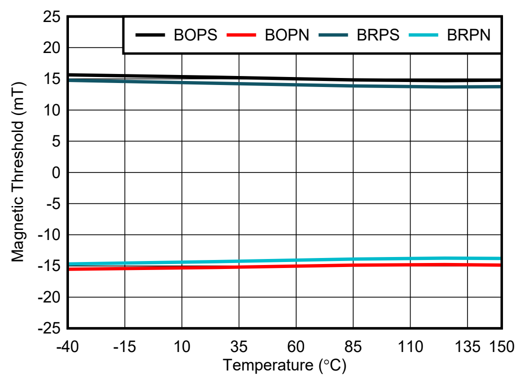
V_{CC} = 3.3V

図 5-3. 7.5mT Magnetic Threshold vs Temperature



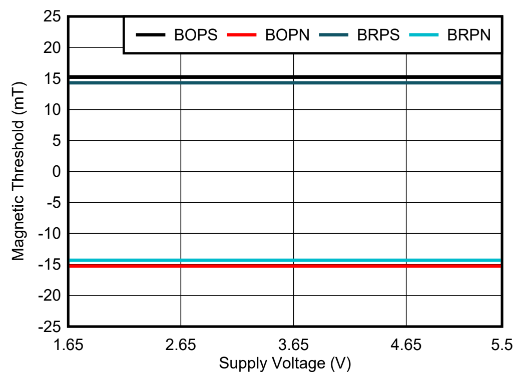
T_A = 25°C

図 5-4. 7.5mT Magnetic Threshold vs Supply



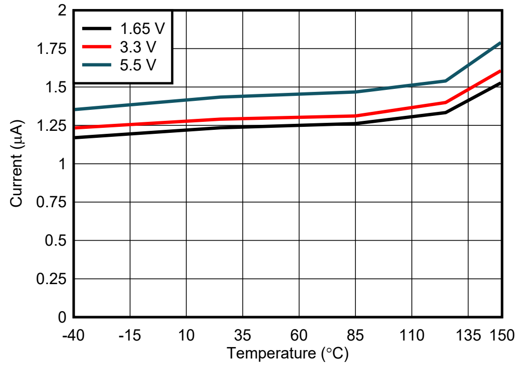
V_{CC} = 3.3V

図 5-5. 15mT Magnetic Threshold vs Temperature



T_A = 25°C

図 5-6. 15mT Magnetic Threshold vs Supply



Sampling Rate = 20Hz

Version: A1D

図 5-7. Average I_{CC} vs Temperature

6 Detailed Description

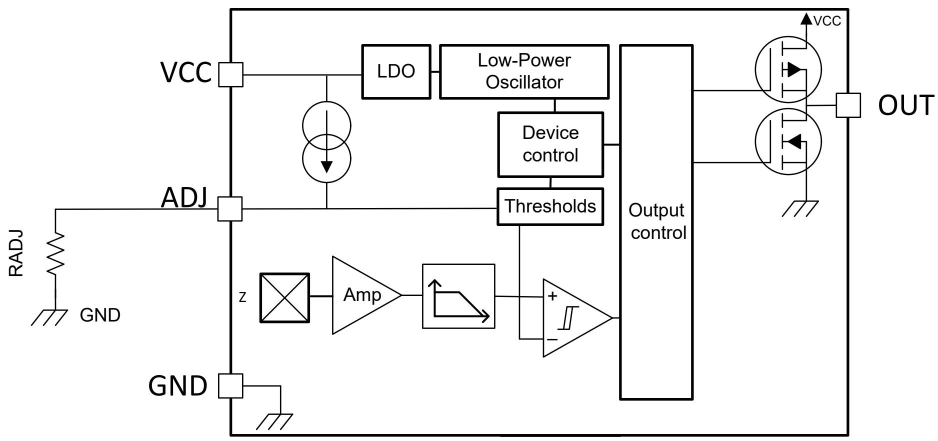
6.1 Overview

The TMAG5328 device is a magnetic sensor with a digital output that indicates when the magnetic flux density threshold has been crossed. The device integrates a Hall effect element, analog signal conditioning, and a low-frequency oscillator that enables ultra-low average power consumption.

While most Hall effect sensors have fixed thresholds, the TMAG5328 offers an extra pin that allows the user to set up a specific threshold of operation. This pin can either be connected to a resistor or a voltage source. While the value can be set at production, it is also possible to allow dynamic change of either the resistor value or the voltage value to dynamically change the threshold value.

Operating from a 1.65V to 5.5V supply, the device periodically measures magnetic flux density, updates the output, and enters into a low-power sleep state.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Magnetic Flux Direction

Magnetic flux that travels from the bottom to the top of the package is considered positive in this data sheet. This condition exists when a south magnetic pole is near the top of the package. Magnetic flux that travels from the top to the bottom of the package results in negative millitesla values.

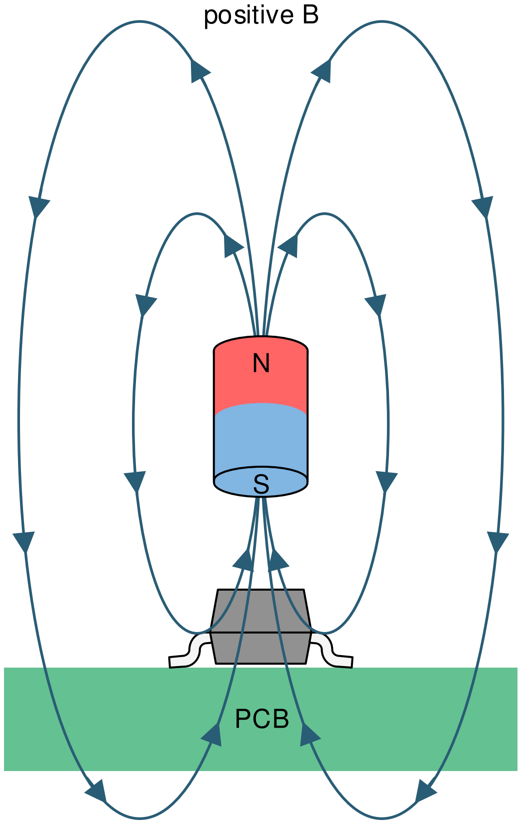


図 6-1. Flux Direction Polarity

6.3.2 Magnetic Response

The TMAG5328A1D and TMAG5328A1Z device versions have an omnipolar functionality, meaning the device responds to both positive and negative magnetic flux densities, as shown in 図 6-2.

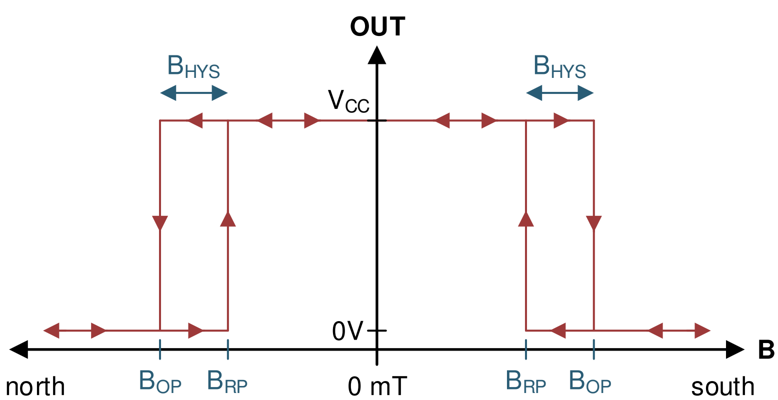


図 6-2. Omnipolar Functionality

6.3.3 Output Type

The TMAG5328A1D and TMAG5328A1Z device versions have a push-pull CMOS output. The push-pull output allows for the lowest system power consumption, because there is no current leakage path when the output drives high or low.

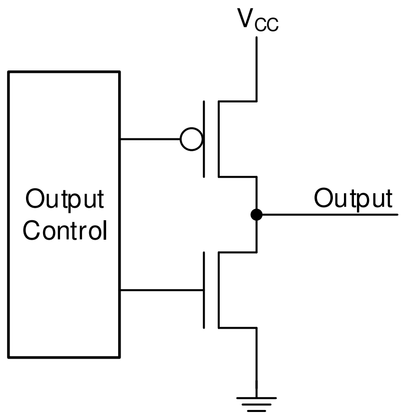


図 6-3. Push-Pull Output (Simplified)

6.3.4 Sampling Rate

When the TMAG5328 device powers up, the device measures the first magnetic sample and sets the output within the t_{ON} time. For the TMAG5328A1D (duty cycled version), the output is latched and the device enters an ultra-low-power sleep state. After each t_{Active} time has passed, the device measures a new sample and updates the output if necessary. If the magnetic field does not change between periods, the output also does not change. While in active mode, the part goes through different steps. The content of the OTP (One-Time-Programmable Memory) is loaded first, and this step takes about 35µs and consumes around 350µA. For the next 5µs, the current source starts up and settles. The part now consumes around 650µA in this step. Finally, the part conducts the Hall sensor conversion for about 25µs and consumes the peak current of around 2mA.

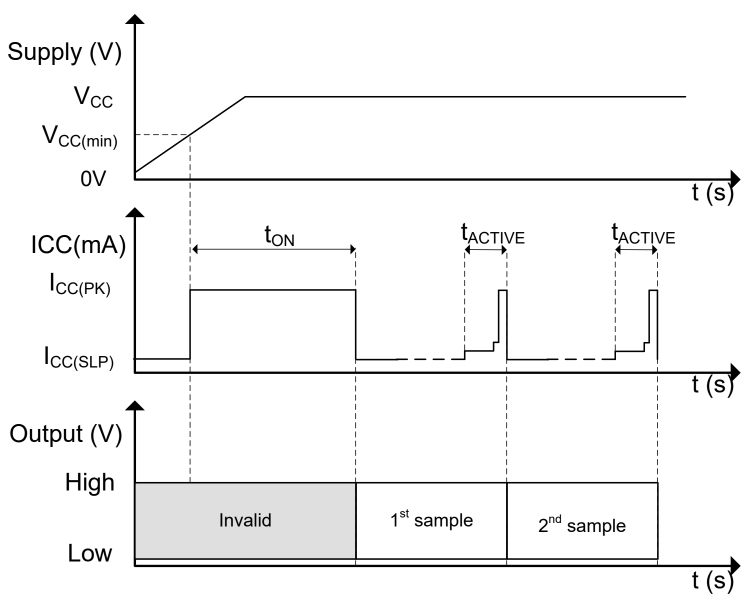


図 6-4. TMAG5328A1D Timing Diagram

The TMAG5328A1Z (continuous time version) stays active after the t_{ON} time has passed (does not go to sleep), enabling a fast signal bandwidth of up to 20kHz (f_{BW}).

6.3.5 Adjustable Threshold

While most Hall Effect switch sensors have fixed magnetic characteristics, the TMAG5328 offers a wide range of adjustable thresholds. The user can use the "ADJ" pin to set the value of B_{OP} threshold. This pin can be used in two different ways. A resistor or a voltage source can be applied on "ADJ". In both scenarios, the resistor or voltage value defines the position of the B_{OP}. While the B_{OP} can be adjusted, the hysteresis has a fixed value. B_{RP} is therefore defined as B_{OP} – Hysteresis.

The TMAG5328A1D (duty cycled version) has an 80μA current generated on pin "ADJ" when the part goes into active mode. The device then reads the "ADJ" pin and defines the value of B_{OP}. The TMAG5328 supports adjusting the B_{OP} dynamically. If the "ADJ" pin value is adjusted while the sensor is in sleep mode, the B_{OP} updates at the next active period of the device. Consequently, the maximum time the internal B_{OP} threshold can take to update for the TMAG5328A1D version is equal to the period of magnetic sampling, t_s (50ms).

The TMAG5328A1Z (continuous time version) has an 80μA current continuously generated on pin "ADJ" to dynamically adjust the B_{OP} threshold if desired. The maximum time the internal B_{OP} threshold can take to update for the TMAG5328A1Z version is 25μs.

6.3.5.1 Adjustable Resistor

One way to set up the B_{OP} is to connect a resistor to the "ADJ" pin. The device generates a fixed current that is injected in the external resistor, and this generates a voltage that represents the B_{OP} value. The relationship between B_{OP} and resistance is defined as B_{OP}(mT) = R_{ADJ}(kΩ). Note that the generated current on the "ADJ" pin is only present when the device is in active mode and turns OFF when the device is in sleep mode. As a result, the voltage on the "ADJ" pin is only present when the device is in active mode, which is a small duration compared to the time the device is in sleep mode.

The device B_{OP} must be set to any value between 2mT and 15mT. This means R_{ADJ} must be set between 2kΩ and 15kΩ. Operating above and beyond those limits is not recommended and can result in either getting the wrong threshold set or locking up the device into a specific state without the possibility of exiting.

図 6-5 shows the relationship between B_{OP} and R_{ADJ}.

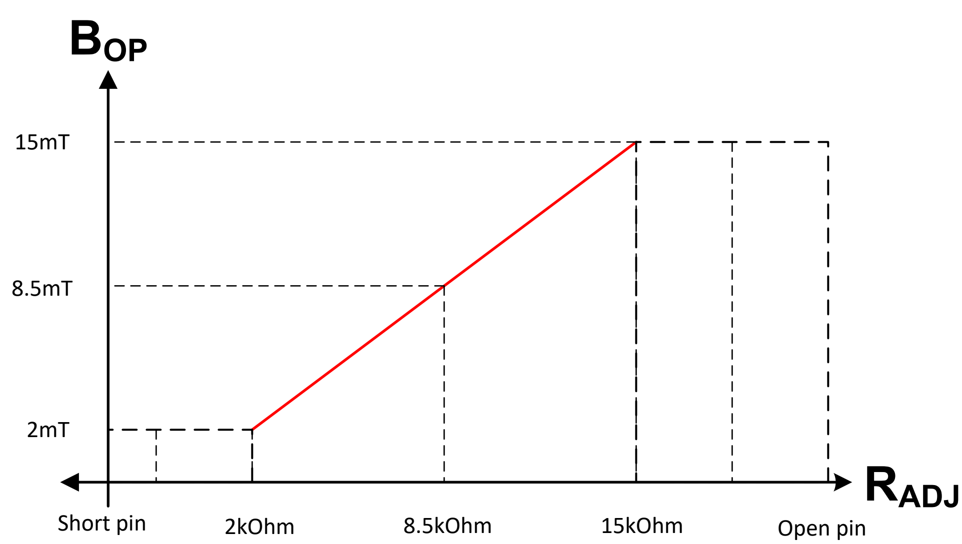


図 6-5. B_{OP} vs R_{ADJ}

6.3.5.2 Adjustable Voltage

One other way to setup the B_{OP} is to apply a voltage to the "ADJ" pin. This voltage is directly proportional to the B_{OP} value. The relationship between B_{OP} and voltage is defined as $B_{OP}(mT) = V_{ADJ}(mV) \times 0.0125$. To apply a voltage on the "ADJ" pin, the voltage source must be able to settle within 4µs after being exposed to a 80µA current on the ADJ pin.

The device B_{OP} must be set to any value between 2mT and 15mT. This means V_{ADJ} must be set between 160mV and 1200mV. Operating above and beyond those limits is not recommended and can result in either getting the wrong threshold set or locking up the device into a specific state without the possibility of exiting.

図 6-6 shows the relationship between B_{OP} and V_{ADJ}.

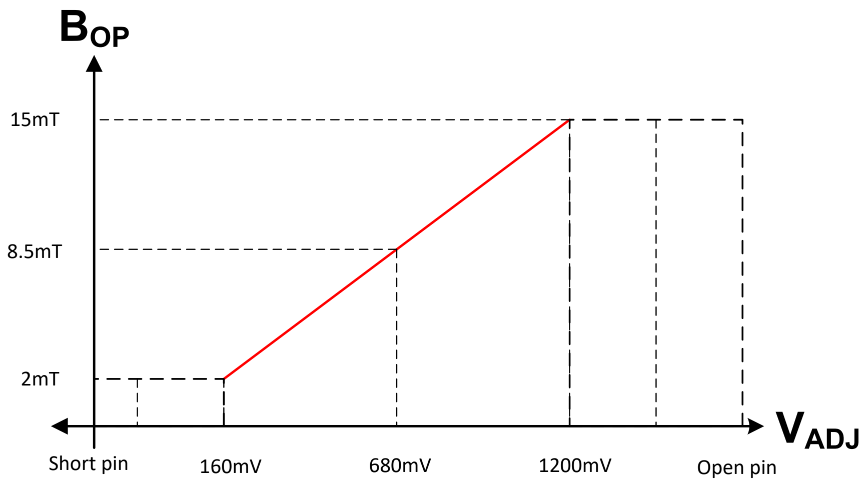


図 6-6. B_{OP} vs R_{ADJ}

6.3.6 Hall Element Location

図 6-7 shows the sensing element location inside the device.

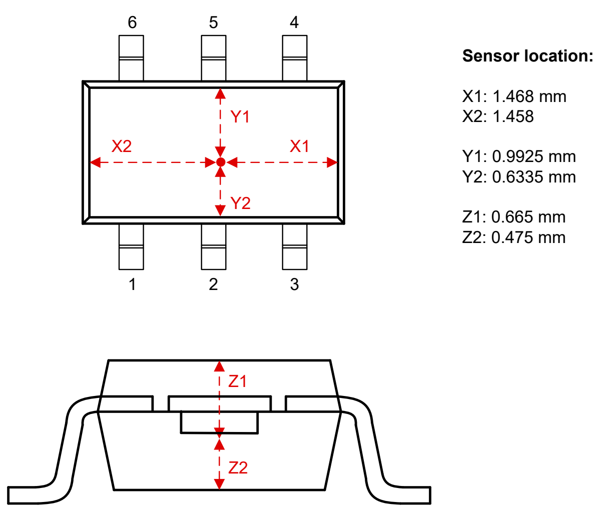


図 6-7. Hall Element Location

6.4 Device Functional Modes

The TMAG5328 device has one mode of operation that applies when the *Recommended Operating Conditions* are met.

7 Application and Implementation

注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

7.1 Application Information

The TMAG5328 device is typically used to detect the proximity of a magnet. The magnet is often attached to a movable component in the system.

7.1.1 Valid TMAG5328 Configurations

The TMAG5328 B_{OP} is set by connecting a resistor or a voltage source to the “ADJ” pin. 図 7-1 shows how to use resistor R1 to set the B_{OP}. 図 7-2 shows hows to use a DAC as a voltage source for setting the B_{OP}. Using the DAC allows the user to dynamically change the B_{OP} with software. To use a DAC, the output of the DAC must settle within 4µs after the 80µA current source of the “ADJ” pin is turned ON.

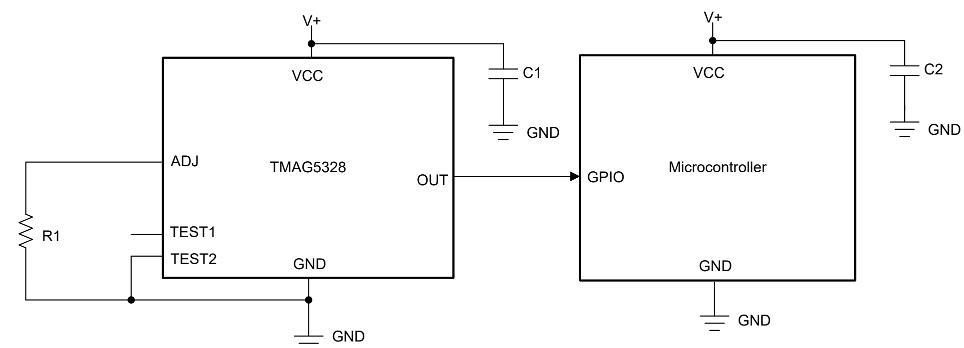


図 7-1. Setting B_{OP} of One TMAG5328 Device Using a Resistor

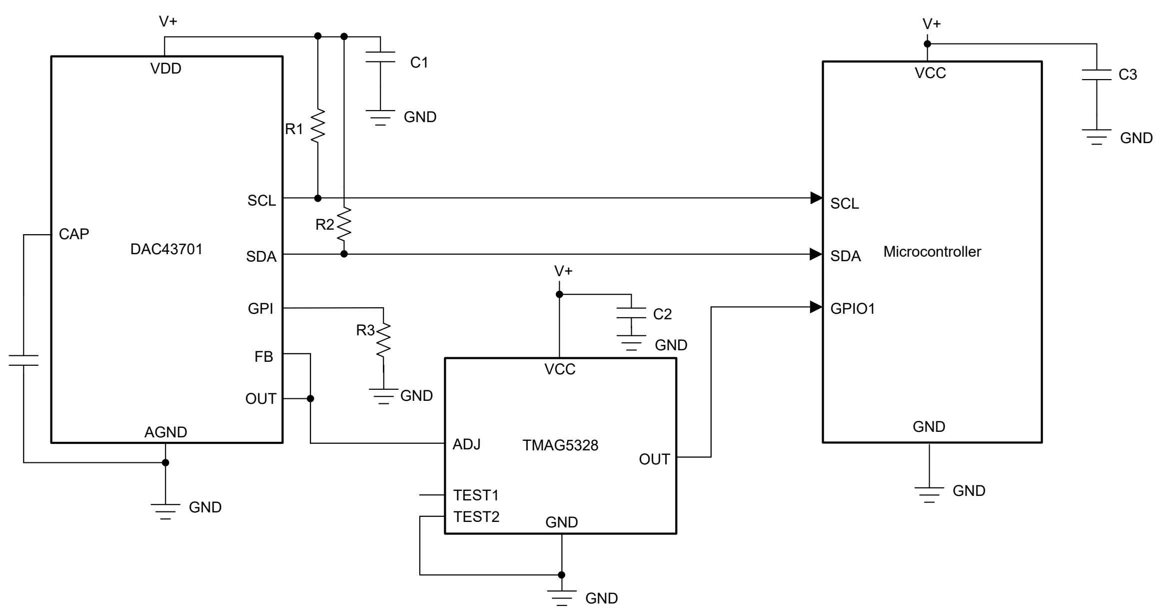


図 7-2. Setting B_{OP} of One TMAG5328 Device Using a DAC

As a DAC alternative, 図 7-3 shows how a voltage divider can be used as a voltage source. In 図 7-3, an operational amplifier is placed between the voltage divider and the “ADJ” pin so that the voltage fed to the “ADJ” pin is not impacted by the internal current source of the TMAG5328 when the current source is turned ON. To use an op amp, the output of the op amp must settle within 4μs after the 80μA current source of the “ADJ” pin is turned ON.

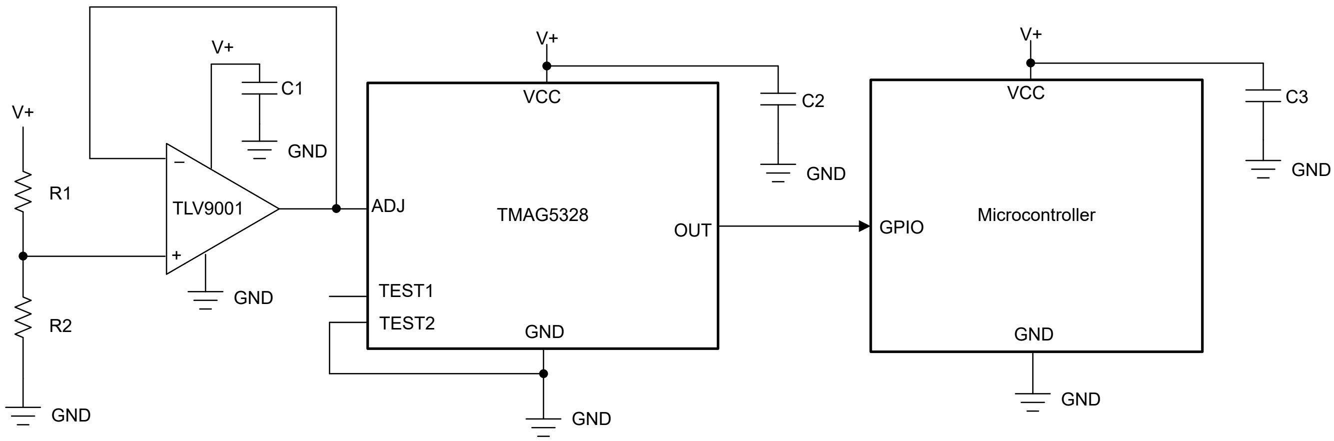


図 7-3. Setting B_{OP} of One TMAG5328 Device Using a Voltage Divider

A potentiometer or rheostat can be integrated into a voltage divider, and the user can adjust this potentiometer to dynamically update the B_{OP}. 図 7-4 shows how to use a potentiometer in a voltage divider to set the B_{OP} of the TMAG5328. The maximum output voltage, which determines the maximum B_{OP}, is set based on the values of resistors R1 and R3. The minimum output voltage, which determines the minimum B_{OP}, is set based on the values of the maximum potentiometer resistance, R1 resistance, and R3 resistance. Select a minimum output voltage greater than 0.16V and a maximum output voltage less than 1.2V.

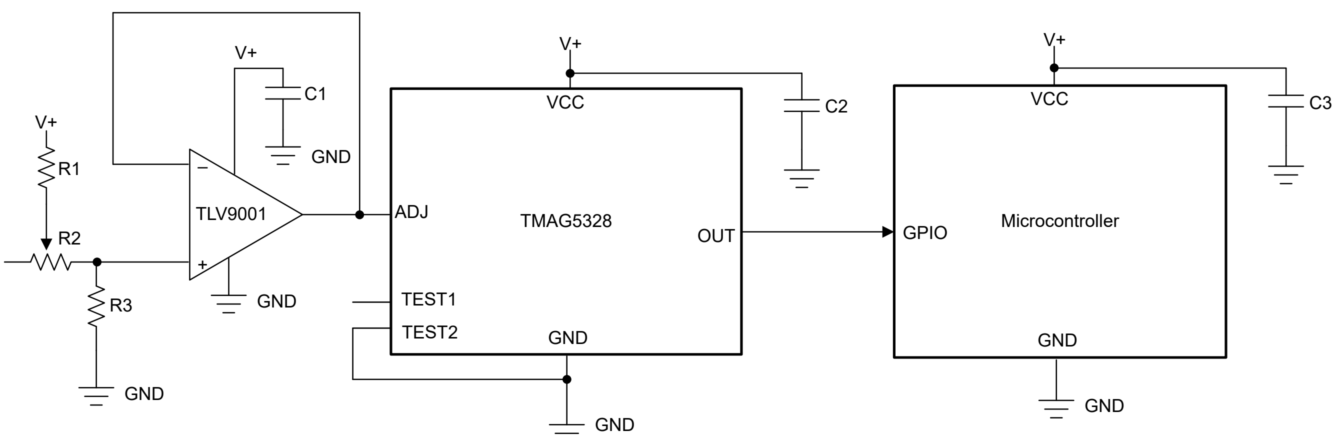


図 7-4. Setting B_{OP} of One TMAG5328 Device Using a Voltage Divider and Potentiometer

図 7-5 shows how the TMAG5328's internal current source can drive a potentiometer or rheostat instead of a voltage divider. In this implementation, make sure the resistor R2 is at least 2kΩ to ensure that the "ADJ" resistance is always above the minimum 2kΩ. The sum of the maximum potentiometer resistance and the resistance of R1 must also be less than 15kΩ.

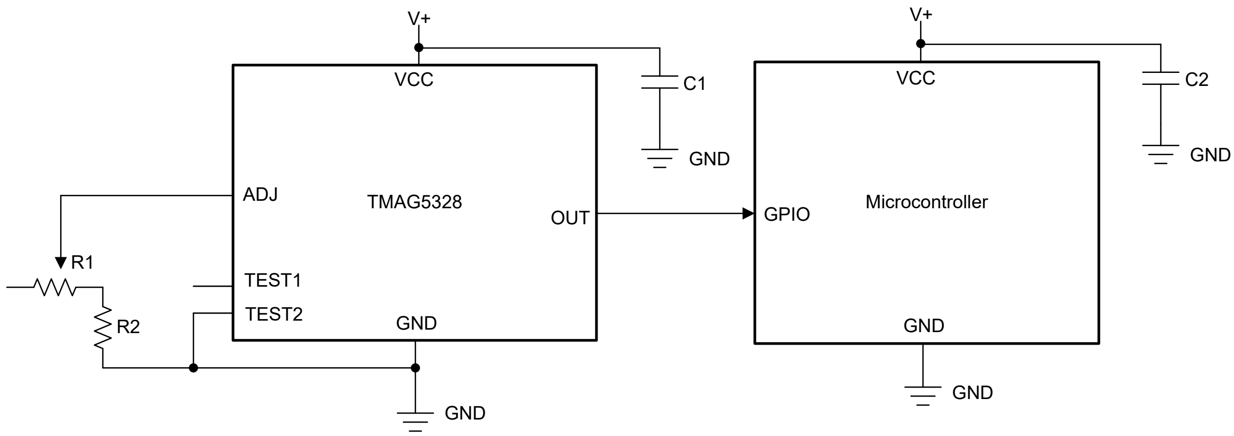


図 7-5. Setting B_{OP} of One TMAG5328 Device Using a Potentiometer and the TMAG5328's Internal Current Source

Multiple TMAG5328 devices can be used in the same system. When setting the B_{OP} using a resistor, TI recommends that each TMAG5328 has a “ADJ” resistor, even if multiple TMAG5328 devices have the same “ADJ” resistor value. 図 7-6 shows an example implementation that has three TMAG5328 devices. If each device is set to the same B_{OP}, then the resistances of R1, R2, and R3 are equal.

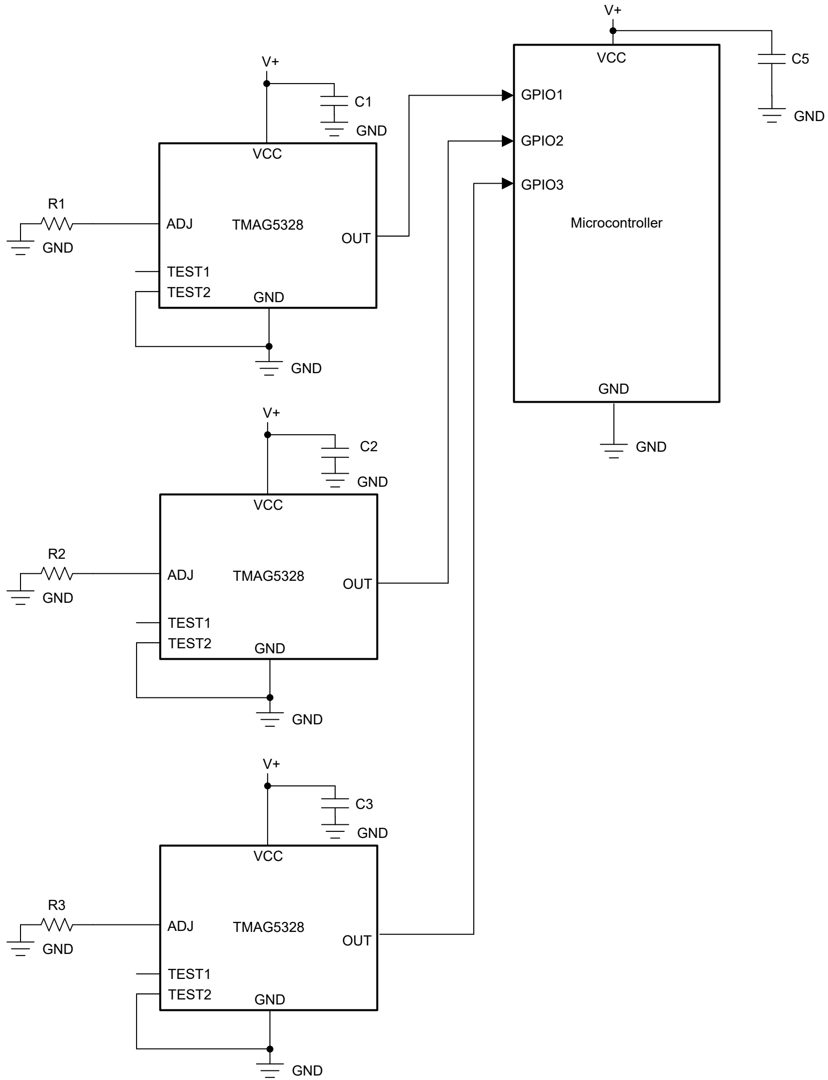


図 7-6. Setting B_{OP} of Three TMAG5328 Devices Using Three Resistors

When setting the B_{OP} using a DAC, one DAC can be used to set the “ADJ” pin voltage of multiple devices only if the output of the DAC can sink the current from all of the TMAG5328 devices. 図 7-7 shows an example of a DAC driving the “ADJ” pin of three TMAG5328 devices. A DAC can only work reliably in this specific scenario if the output of the DAC can settle within 4μs after being exposed to the three “ADJ” current sources. Each current source is 80μA, therefore the DAC can only reliably work if the output of the DAC can settle within 4μs after being exposed to 80 x 3 = 240μA of current.

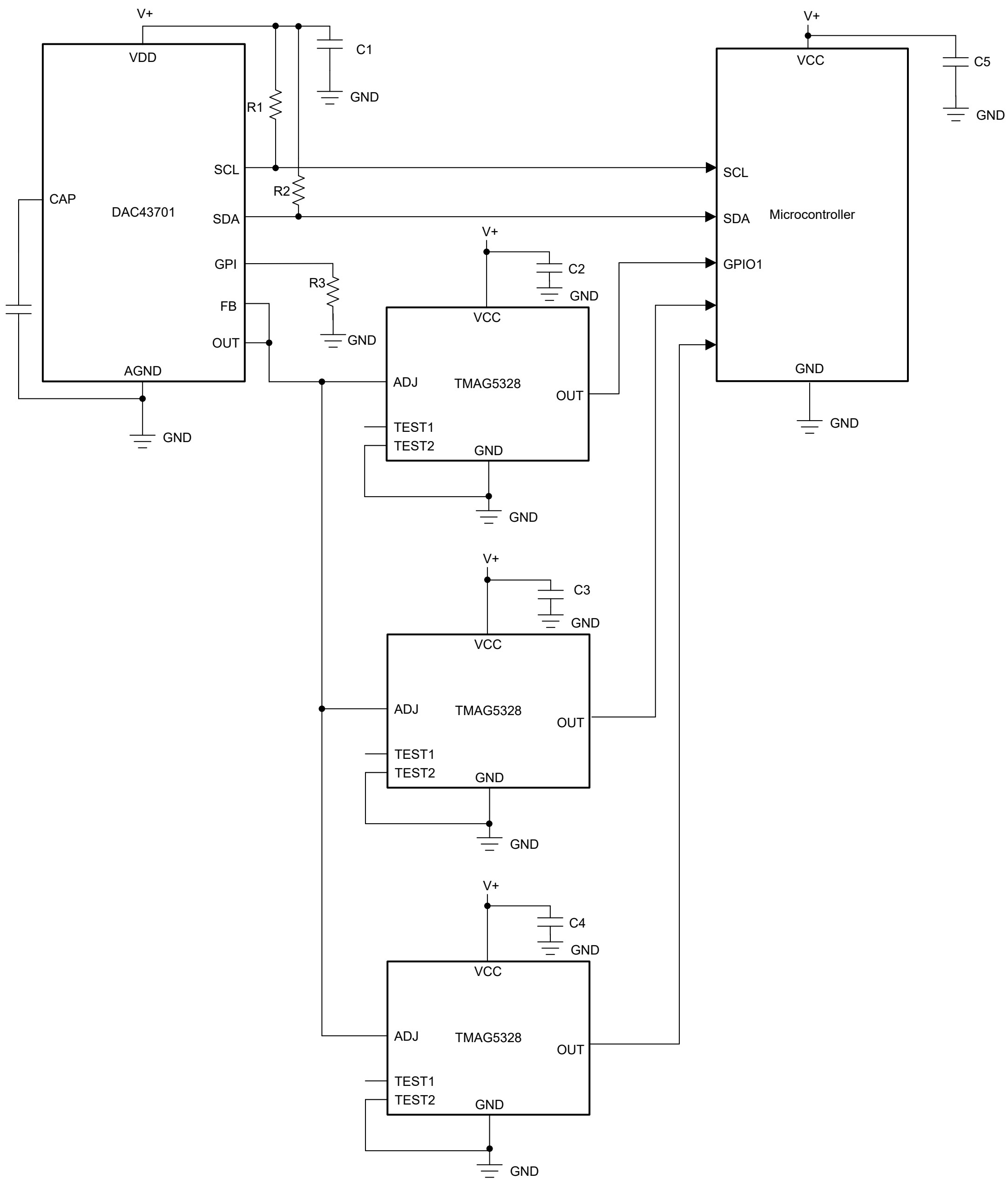


図 7-7. Setting B_{OP} of Three TMAG5328 Devices Using a DAC

7.2 Typical Applications

The TMAG5328 can be used in a large variety of industrial applications. For almost all these applications, the sensor is fixed and the magnet is attached to a movable component in the system.

7.2.1 Refrigerator Door Open/Close Detection

This application section describes how to use the same device for two identical applications with different mechanical characteristic.

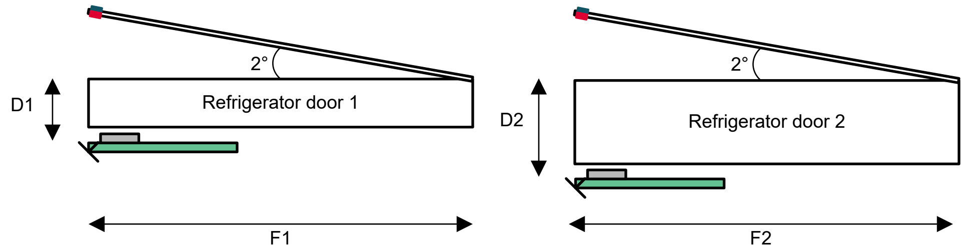


図 7-8. Refrigerator 1 and Refrigerator 2 Principal Diagram

7.2.1.1 Design Requirements

For this design example, use the parameters listed in 表 7-1.

表 7-1. Design Parameters for Fridge 1

DESIGN PARAMETER	EXAMPLE VALUE
Hall effect device	TMAG5328A1D
V_{CC}	5V
Magnet	10mm cubic N35
D1	7.025mm
F1	500mm
Door opening angle	2°
Calculated threshold needed (B_{OP})	7.87mT
R_{ADJ}	7.87kΩ

表 7-2. Design Parameters for Fridge 2

DESIGN PARAMETER	EXAMPLE VALUE
Hall effect device	TMAG5328A1D
V_{CC}	5V
Magnet	10mm cubic N35
D2	16.08mm
F2	500mm
Door opening angle	2°
Calculated threshold needed (B_{OP})	3.49mT
R_{ADJ}	3.48kΩ

7.2.1.2 Detailed Design Procedure

For both applications, the Hall sensor is used to detect if the refrigerator door is open or closed. Both refrigerator doors are different from each other and therefore have different mechanical design. This means the Hall sensor and the magnet are positioned differently from each other. In other terms, if the user wants to detect a specific distance for both refrigerator doors, they must use either a different magnet or a different sensor. For the purpose of this application, there is no flexibility in the choice of magnet. The electronic board can also be reused across platforms and therefore can use the same sensor.

The TMAG5328 is a resistor adjustable Hall effect switch that allows the user to set up whatever threshold is needed between 2mT and 15mT.

For this application, the refrigerator door manufacturer can use the same printed circuit board (PCB) with the same semiconductor content and only has to change the resistor value depending on which refrigerator version is manufactured.

For both refrigerator doors, the opening angle is the same. Now refrigerator door 1 is a thinner model than refrigerator door 2. This means the PCB is located further away for refrigerator door 2 and therefore the sensitivity required to detect the position of the door is impacted.

Knowing the door dimensions, the door opening angle required, and the distance from the magnet to the PCB, it is possible to use a simulation tool that can calculate the magnet strength at the desired position. For refrigerator door 1, the sensitivity calculated is 7.87mT at a distance of 7.025mm. For Refrigerator 2, the sensitivity is 3.49mT at a distance of 16.08mm. Based on those values, a resistor value can be selected from the E48 series. A resistor of 7.87kΩ can be used for refrigerator door 1 and resistor of 3.48kΩ can be used for refrigerator door 2.

7.3 Power Supply Recommendations

The TMAG5328 device is powered from 1.65V to 5.5V DC power supplies. A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.1µF.

7.4 Layout

7.4.1 Layout Guidelines

Magnetic fields pass through most non-ferromagnetic materials with no significant disturbance. Embedding Hall effect sensors within plastic or aluminum enclosures and sensing magnets on the outside is common practice. Magnetic fields also easily pass through most printed circuit boards, which makes placing the magnet on the opposite side possible.

7.4.2 Layout Example

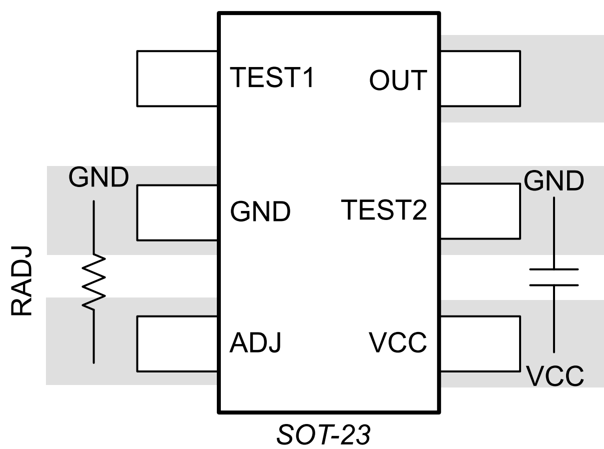


図 7-9. SOT-23 Layout Example

8 Device and Documentation Support

8.1 Device Nomenclature

図 8-1 shows a legend for reading the complete device name for the TMAG5328.

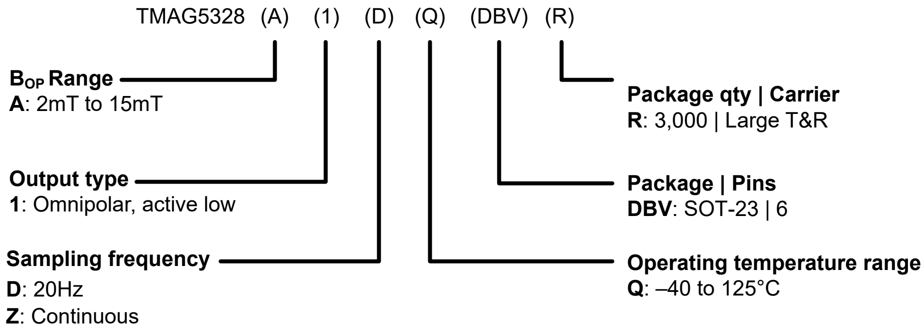


図 8-1. TMAG5328 Device Nomenclature

8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。 変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.3 サポート・リソース

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.6 用語集

テキサス・インスツルメンツ用語集　　この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

Changes from Revision A (June 2022) to Revision B (May 2024)	Page
• A1Z デバイス バージョンをデータシートに追加	1

Changes from Revision * (December 2021) to Revision A (June 2022)	Page
• データシートのステータスを「事前情報」から「*量産データ*」へ*変更*	1

10 メカニカル、パッケージ、および注文情報

以下のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、指定のデバイスに対して提供されている最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版については、左側のナビゲーションをご覧ください。

重要なお知らせと免責事項

郵送先住所：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TMAG5328A1DQDBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	A1D	Samples
TMAG5328A1ZQDBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	A1Z	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

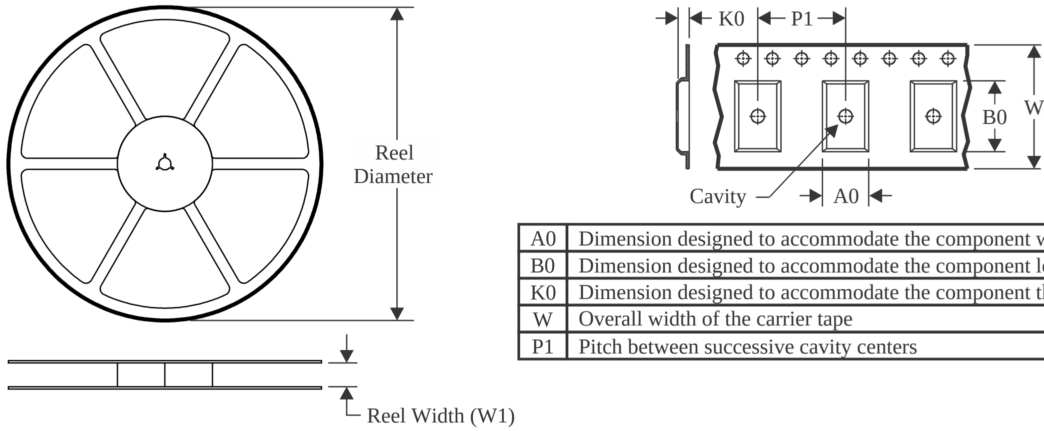
(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

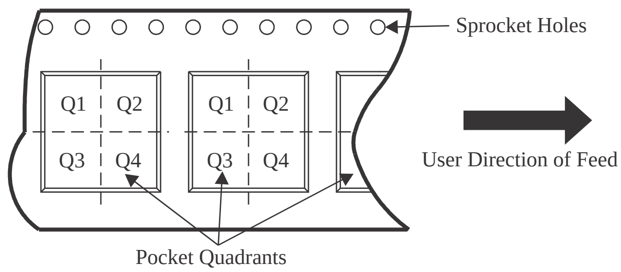
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION



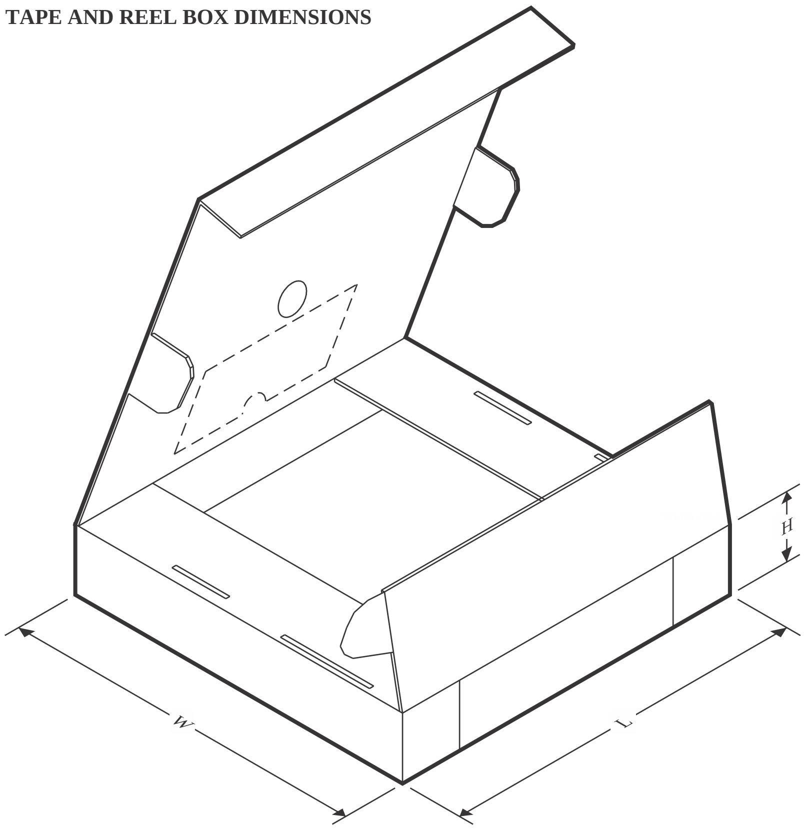
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMAG5328A1DQDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TMAG5328A1ZQDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

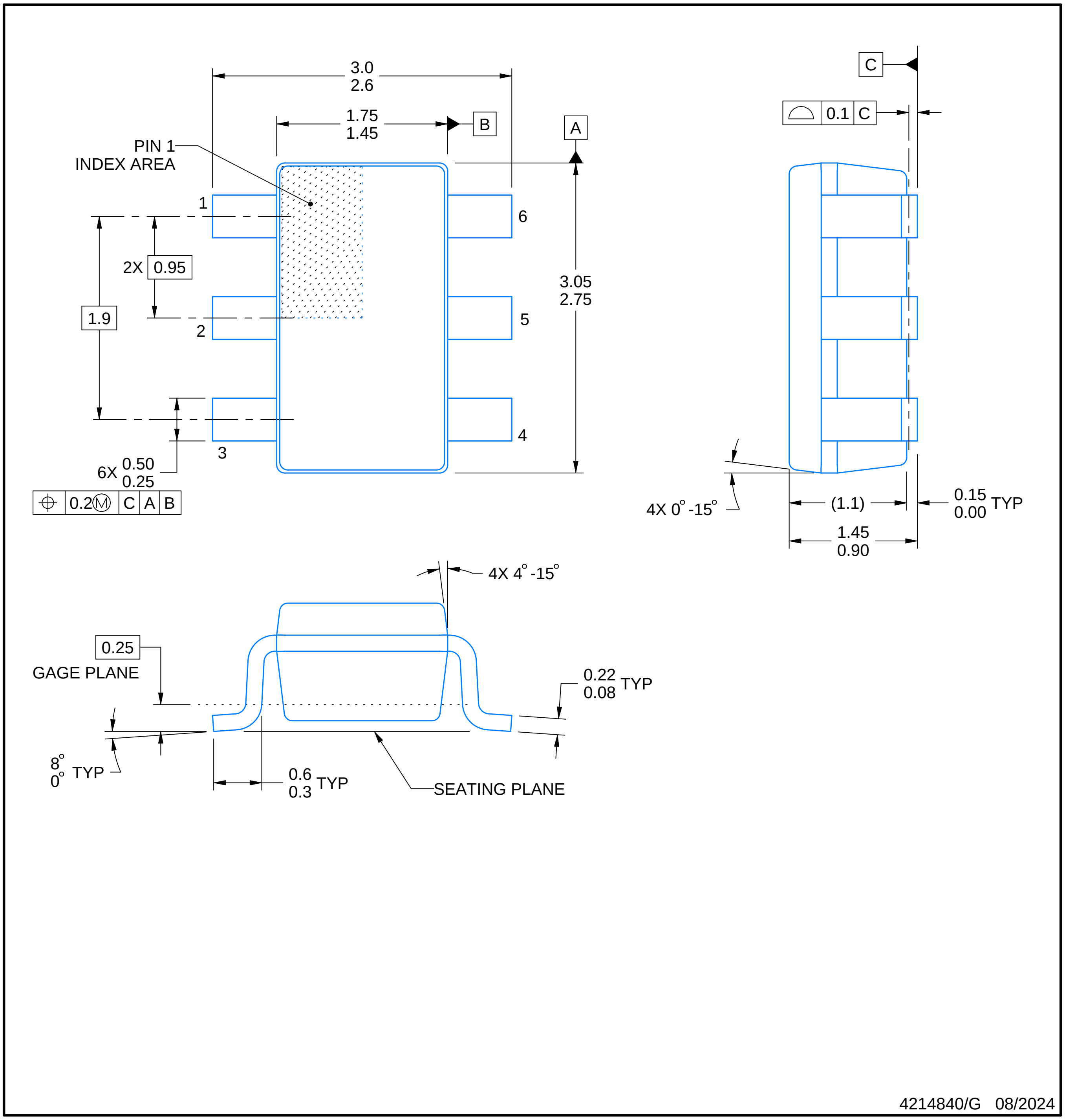
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMAG5328A1DQDBVR	SOT-23	DBV	6	3000	190.0	190.0	30.0
TMAG5328A1ZQDBVR	SOT-23	DBV	6	3000	190.0	190.0	30.0

PACKAGE OUTLINE

DBV0006A

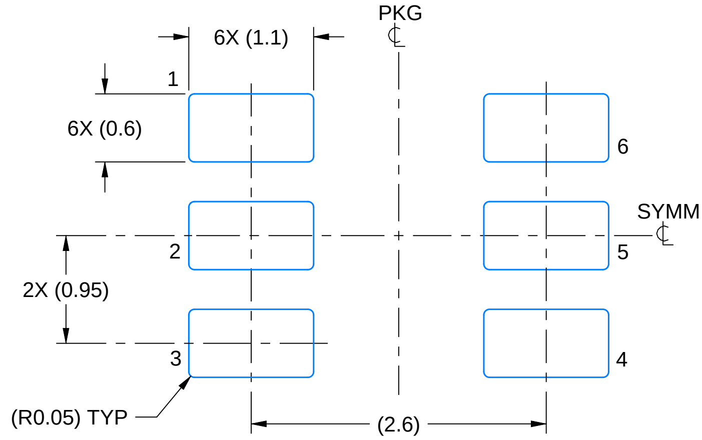
SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

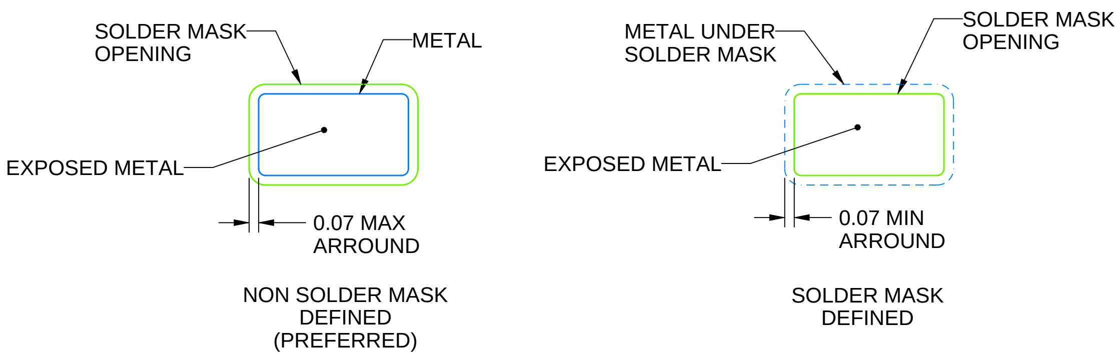


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

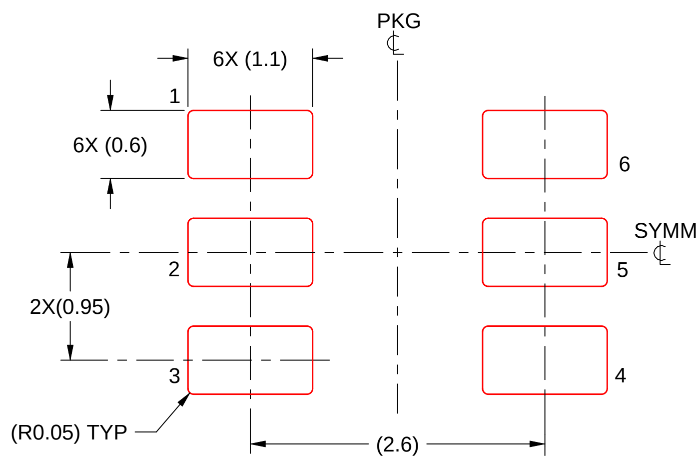


SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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